



JCS4N65C

JCS4N65C

主要参数 MAIN CHARACTERISTICS

ID	4.0 A
V _{DSS}	650 V
R _{dson} (V _{gs} =10V)	Typ 2.1 Ω
	Max 2.6 Ω
Q _{g-typ} 14nC	

用途

- 高频开关电源
- 电子镇流器
- LED 电源

APPLICATIONS

- High frequency switching mode power supply
- Electronic ballast
- LED power supply

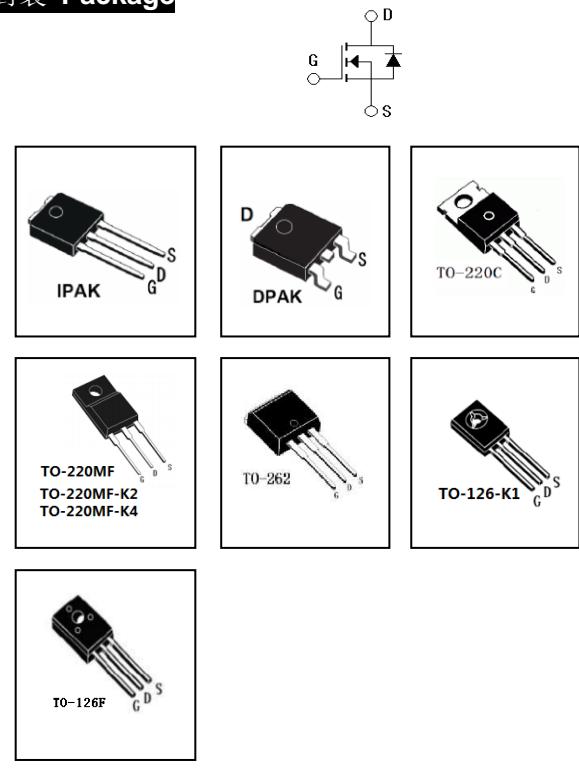
产品特性

- 低栅极电荷
- 低 C_{rss} (典型值 12pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

FEATURES

- Low gate charge
- Low C_{rss} (typical 12pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
JCS4N65VC-V-B	JCS4N65VC-V-BR	N/A	N/A	JCS4N65V	IPAK
JCS4N65RC-R-B	JCS4N65RC-R-BR	JCS4N65RC-R-A	JCS4N65RC-R-AR	JCS4N65R	DPAK
JCS4N65CC-C-B	JCS4N65CC-C-BR	N/A	N/A	JCS4N65C	TO-220C
JCS4N65FC-F-B	JCS4N65FC-F-BR	N/A	N/A	JCS4N65F	TO-220MF
JCS4N65FC-F2-B	JCS4N65FC-F2-BR	N/A	N/A	JCS4N65F	TO-220MF-K2
JCS4N65FC-F4-B	JCS4N65FC-F4-BR	N/A	N/A	JCS4N65F	TO-220MF-K4
JCS4N65BC-B-B	JCS4N65BC-B-BR	N/A	N/A	JCS4N65B	TO-262
JCS4N65MC-M-B	JCS4N65MC-M-BR	N/A	N/A	JCS4N65M	TO-126-K1
JCS4N65MFC-MF-B	JCS4N65MFC-MF-BR	N/A	N/A	JCS4N65MF	TO-126F



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JILIN SINO-MICROELECTRONICS CO., LTD



JCS4N65C

绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value				单 位 Unit		
		JCS4N65VC/ RC/BC/MC/M FC	JCS4N6 5CC	JCS4N6 5FC	JCS4N65F C-K2/K4			
最高漏极—源极直流电压 Drain-Source Voltage	V _{DSS}	650			V			
连续漏极电流 Drain Current -continuous	I _D T=25°C T=100°C	4.0		4.0*		A		
		3.2		2.5*		A		
最大脉冲漏极电流 (注 1) Drain Current - pulse (note 1)	I _{DM}	16		16*		A		
最高栅源电压 Gate-Source Voltage	V _{GSS}	±30				V		
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy note 2)	E _{AS}	256				mJ		
雪崩电流 (注 1) Avalanche Current (note 1)	I _{AR}	4.0				A		
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	E _{AR}	11.0				mJ		
二极管反向恢复最大电压变化 速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	5.5				V/ns		
耗散功率 Power Dissipation	P _D T _C =25°C -Derate above 25°C	122	138	49.8	38.8	W		
		0.976	1.104	0.398	0.311	W/°C		
最高结温及存储温度 Operating and Storage Temperature Range	T _J , T _{STG}	-55~+150				°C		
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T _L	300				°C		

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature



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版本: 201810T

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JCS4N65C

电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最 小 Min	典 型 Typ	最 大 Max	单 位 Units
关态特性 Off -Characteristics						
漏一源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	650	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$, referenced to $25^\circ C$	-	0.65	-	V/ $^\circ C$
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=650V, V_{GS}=0V, T_C=25^\circ C$	-	-	10	μA
		$V_{DS}=520V, T_C=125^\circ C$	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=2.0A$ $25^\circ C$	-	2.1	2.6	Ω
		$V_{GS}=10V, I_D=2.0A$ $100^\circ C$	-	3.68	4.2	Ω
		$V_{GS}=10V, I_D=2.0A$ $150^\circ C$	-	5.46	6.2	Ω
正向跨导 Forward Transconductance	g_{fs}	$V_{DS}=40V, I_D=2.0A$ (note 4)	-	4.5	-	S
动态特性 Dynamic Characteristics						
栅极电阻 Gate resistance	R_g	F=1.0MHz open drain	0.8	-	5.5	Ω
输入电容 Input capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	200	490	810	pF
输出电容 Output capacitance	C_{oss}		20	60	100	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		1	3.5	10	pF





电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_d(\text{on})$	$V_{DD}=325V, I_D=4.0A, R_G=25\Omega$ (note 4, 5)	-	49	100	ns
上升时间 Turn-On rise time	t_r		-	62	120	ns
延迟时间 Turn-Off delay time	$t_d(\text{off})$		-	81	160	ns
下降时间 Turn-Off Fall time	t_f		-	21	50	ns
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=520V, I_D=4.0A$ $V_{GS}=10V$ (note 4, 5)	-	14	22	nC
栅一源电荷 Gate-Source charge	Q_{gs}		-	3	7.0	nC
栅一漏电荷 Gate-Drain charge	Q_{gd}		-	5	10.0	nC

漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings

正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	I_S			-	-	4	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}			-	-	16	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=4.0A$		-	-	1.4	V
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=4.0A$ $dI_F/dt=100A/\mu s$ (note 4)		-	280	800	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}			-	2.0	6.8	μC

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max				单 位 Unit
		JCS4N65 VC/RC/BC/MC /MFC	JCS4N65 CC	JCS4N65FC (TO-220MF)	JCS4N65FC (TO-220MF-K2/K4)	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	1.02	0.905	2.51	3.22	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	73.14	59.3	41.3	48.68	°C/W

注释:

- 1: 脉冲宽度由最高结温限制
- 2: $L=46mH, I_{AS}=4.0A, V_{DD}=50V, R_G=25\Omega$, 起始结温 $T_J=25^\circ C$
- 3: $I_{SD} \leq 4.0A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$, 起始结温 $T_J=25^\circ C$
- 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$, 占空比 $\leq 2\%$
- 5: 基本与工作温度无关

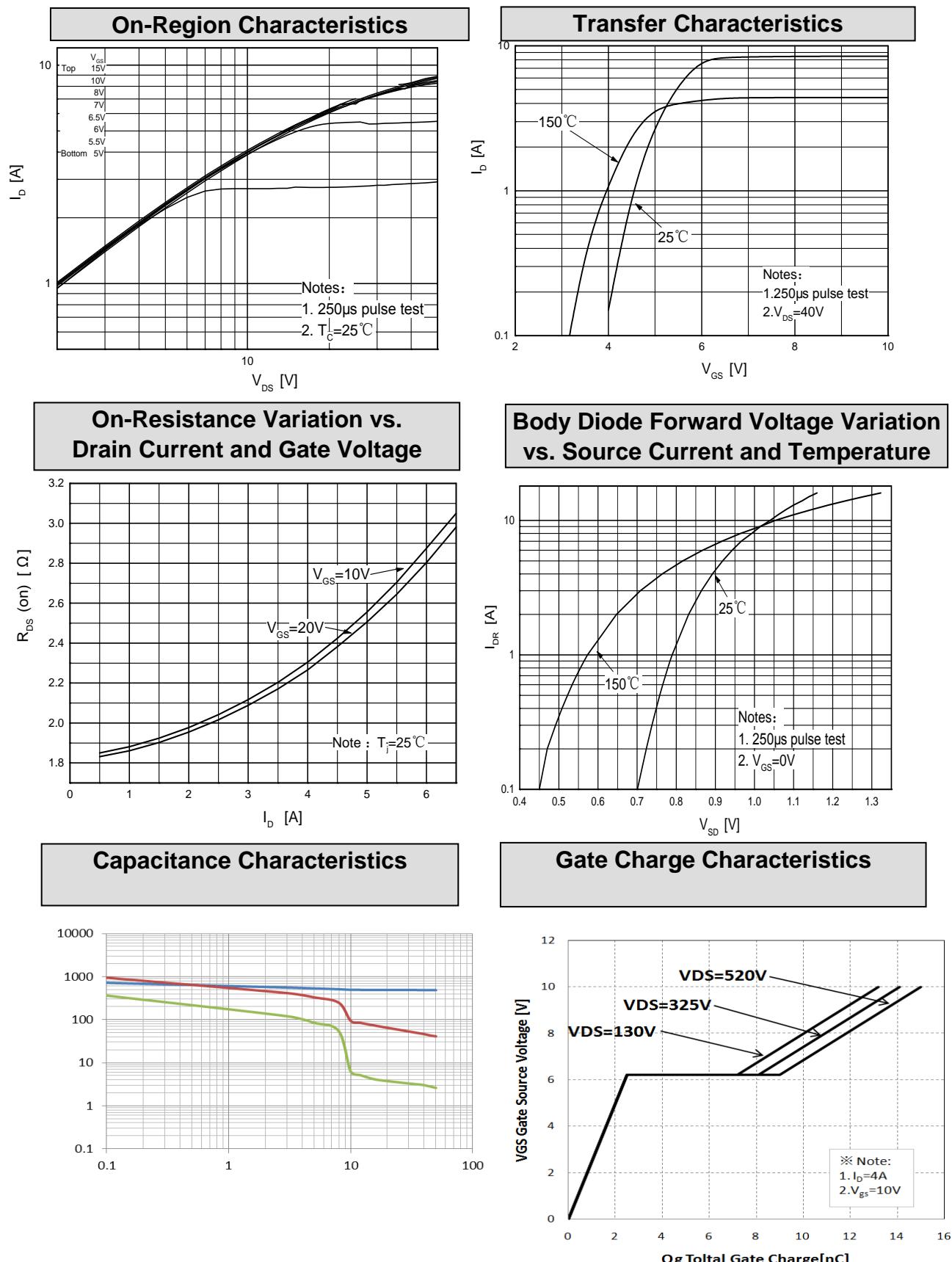
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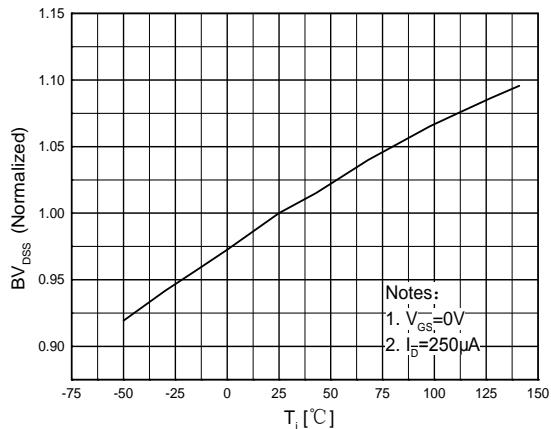
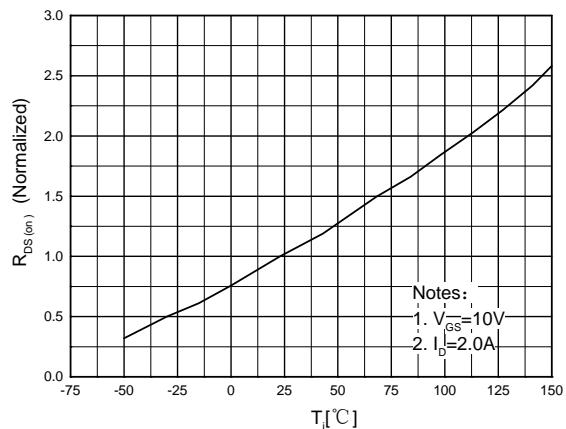
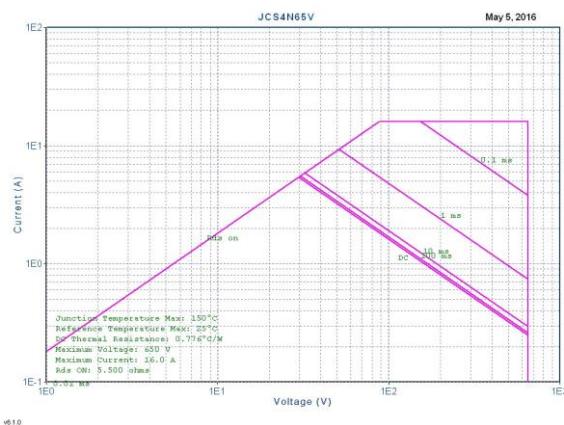
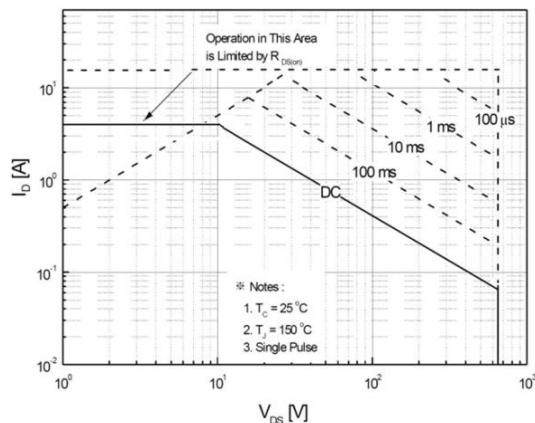
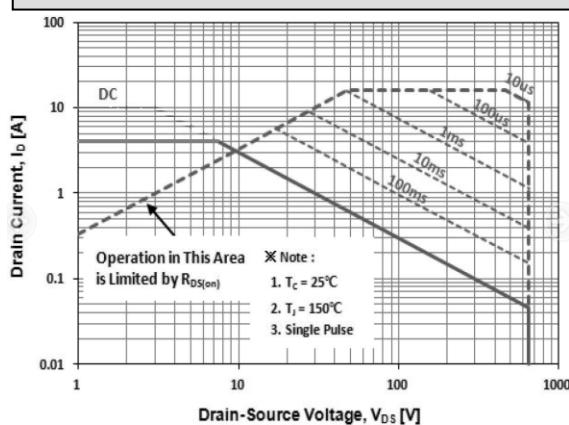
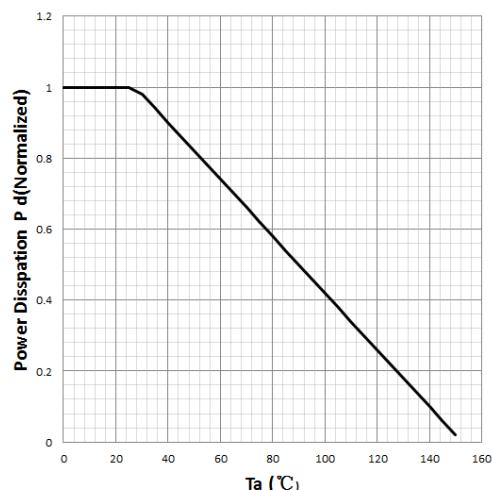
- 1: Pulse width limited by maximum junction temperature
- 2: $L=46mH, I_{AS}=4.0A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^\circ C$
- 3: $I_{SD} \leq 4.0A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^\circ C$
- 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycles $\leq 2\%$
- 5: Essentially independent of operating temperature



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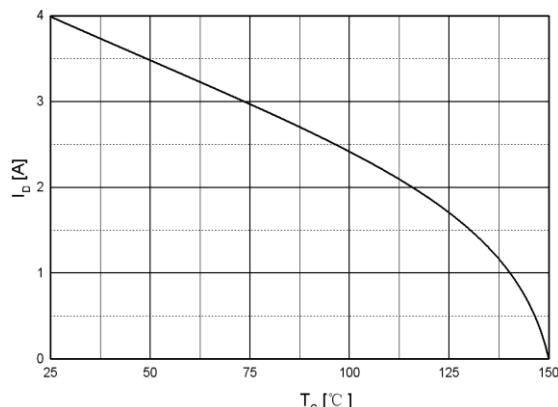
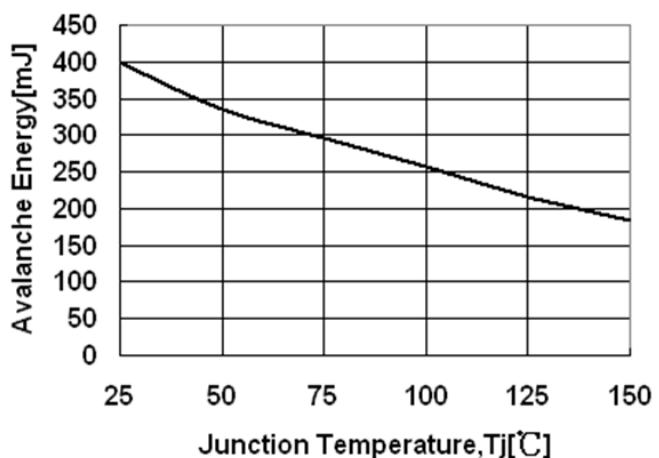
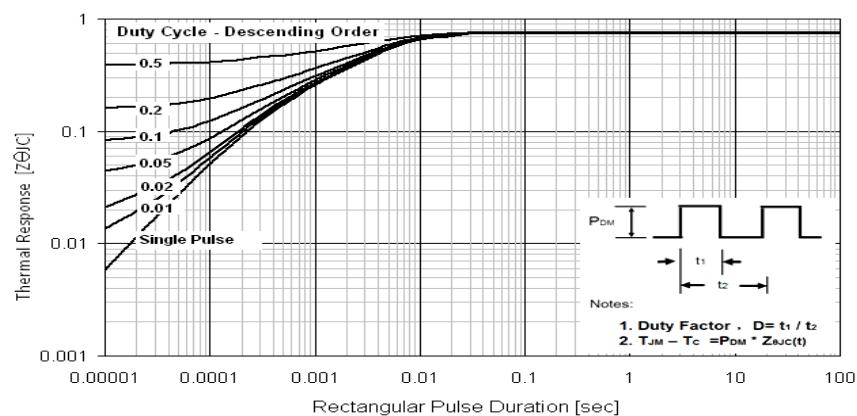
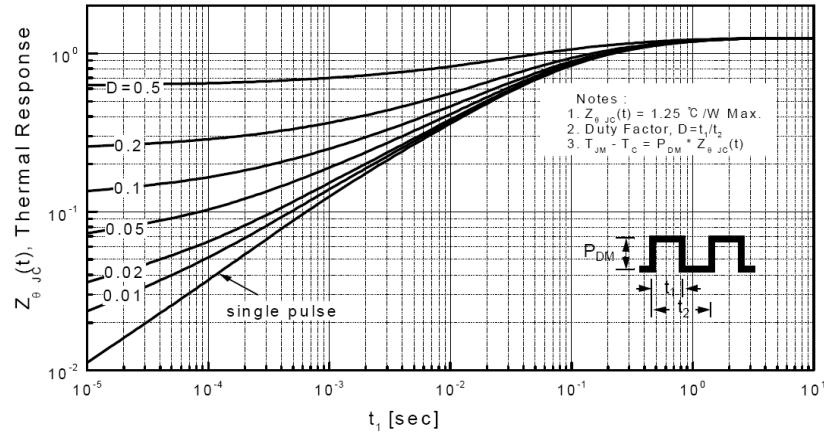
特征曲线 ELECTRICAL CHARACTERISTICS (curves)


特征曲线 ELECTRICAL CHARACTERISTICS (curves)
**Breakdown Voltage Variation
vs. Temperature**

**On-Resistance Variation
vs. Temperature**

**Maximum Safe Operating Area
For JCS4N65V/R/C/B/M/MF C**

**Maximum Safe Operating Area
For JCS4N65FC(TO-220MF)**

**Maximum Safe Operating Area
For JCS4N65FC(TO-220MF-K2/K4)**

**Power Dissipation vs.
Temperature**




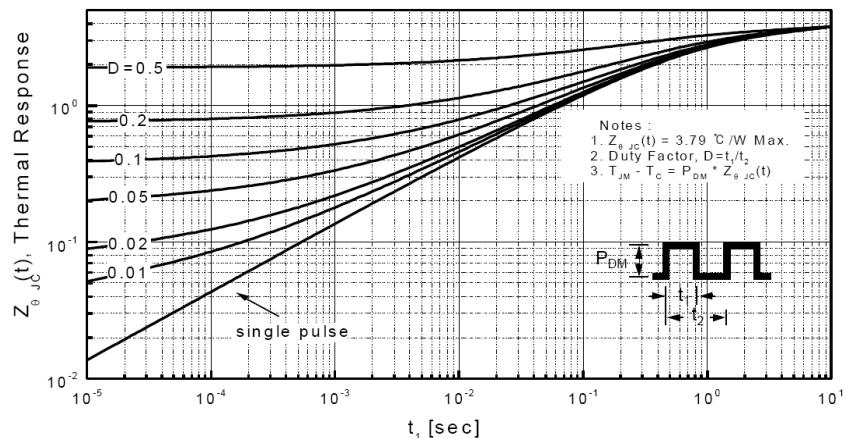
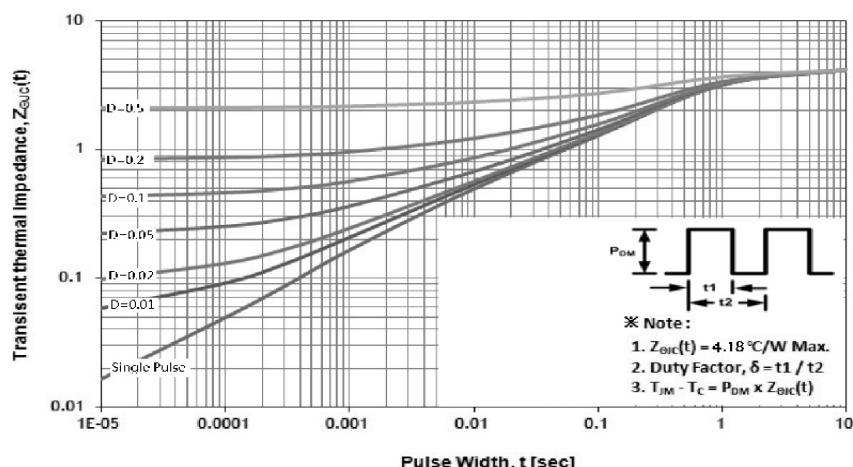
JCS4N65C

特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Maximum Drain Current
vs. Case TemperatureAvalanche Energy
vs. TemperatureTransient Thermal Response Curve
For JCS4N65VC/RC/BC/MC/MFCTransient Thermal Response Curve
For JCS4N65CC



特征曲线 ELECTRICAL CHARACTERISTICS (curves)

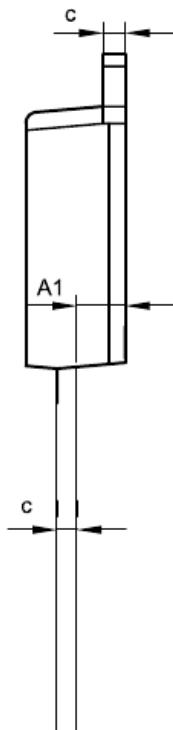
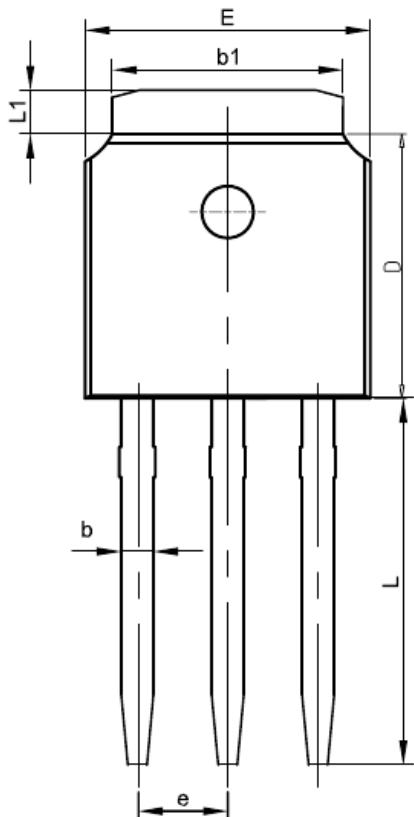
Transient Thermal Response Curve
For JCS4N65FC(TO-220MF)Transient Thermal Response Curve
For JCS4N65FC(TO-220MF-K2/K4)



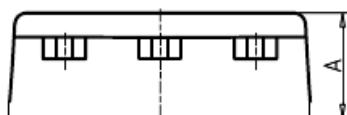
JCS4N65C

外形尺寸 PACKAGE MECHANICAL DATA
IPAK

单位 Unit: mm



SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22



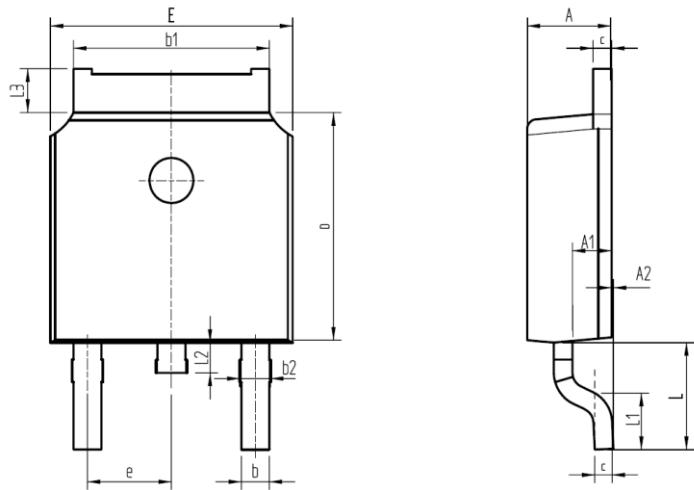


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外形尺寸 PACKAGE MECHANICAL DATA

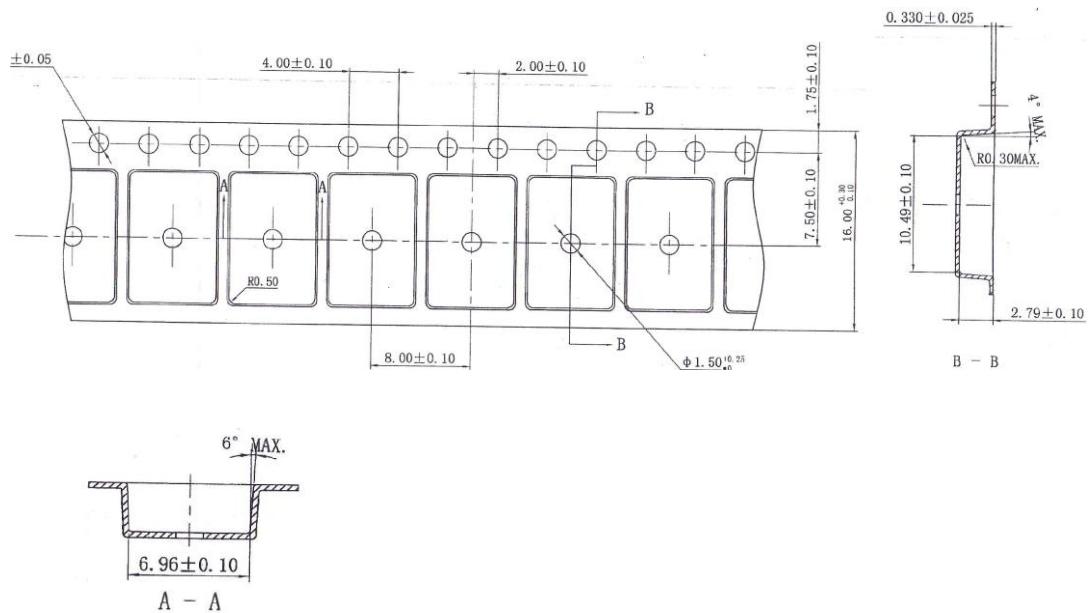
DPAK

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30

编带 REEL



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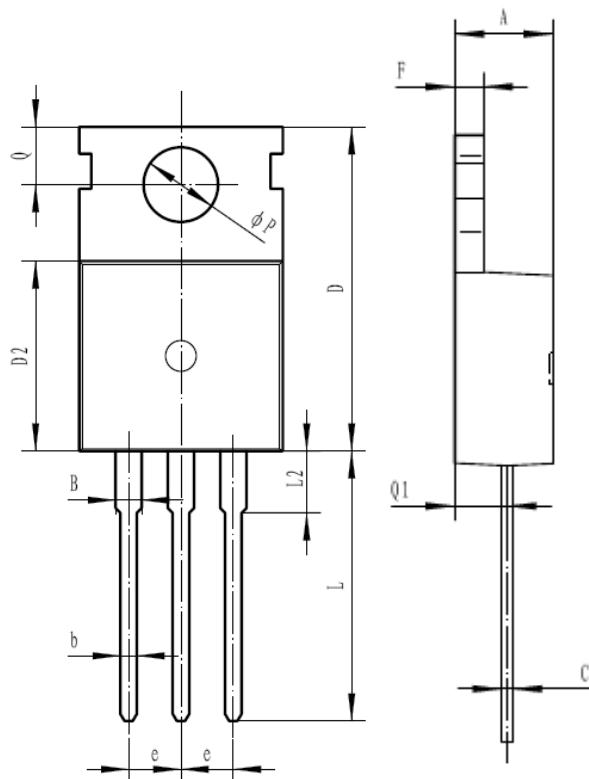


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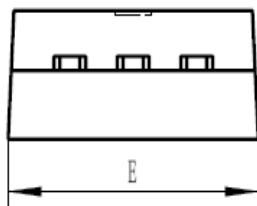
外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit: mm



符号 symbol	MIN	MAX
A	4.30	4.70
B	1.22	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

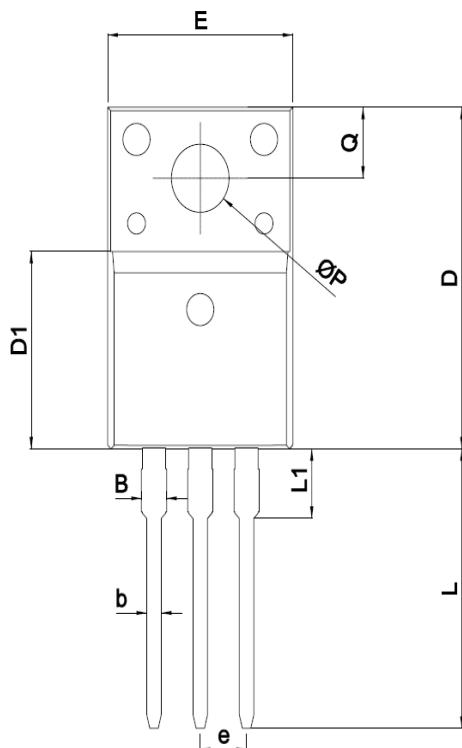




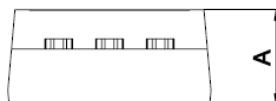
外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54	TYPE
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28

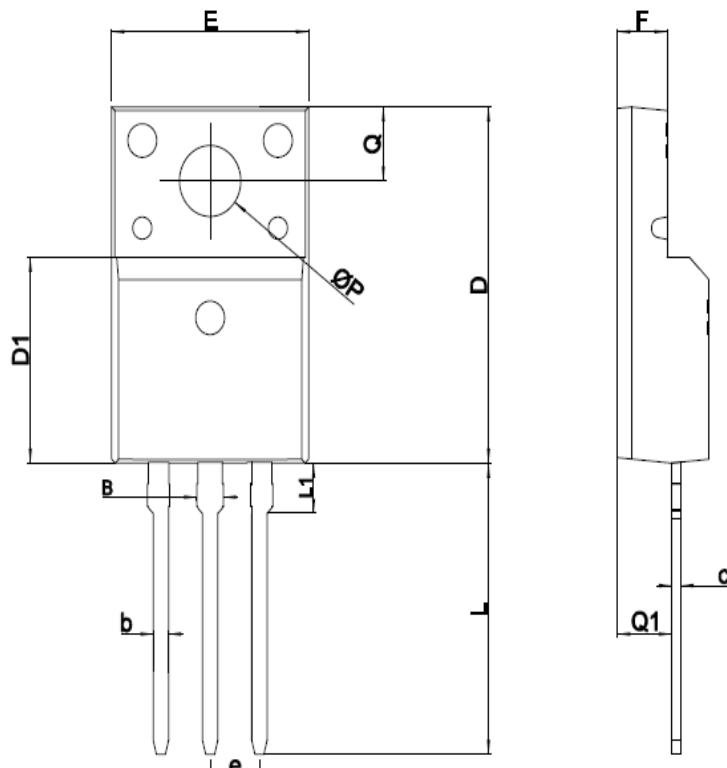




外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K2

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.27
b	0.59	0.79
c	0.45	0.60
D	15.67	16.07
D1	8.97	9.37
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.65	13.35
L1	1.80	2.20
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28

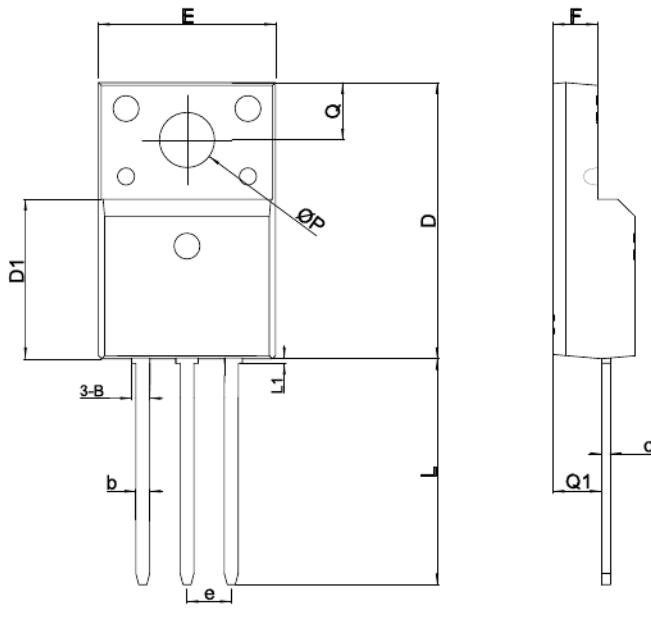




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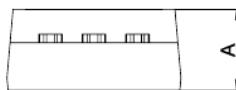
外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K4



单位 Unit: mm

SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B	1.04	1.24
b	0.59	0.79
c	0.45	0.60
D	15.67	16.07
D1	8.97	9.37
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.65	13.35
L1	MAX 0.95	
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28

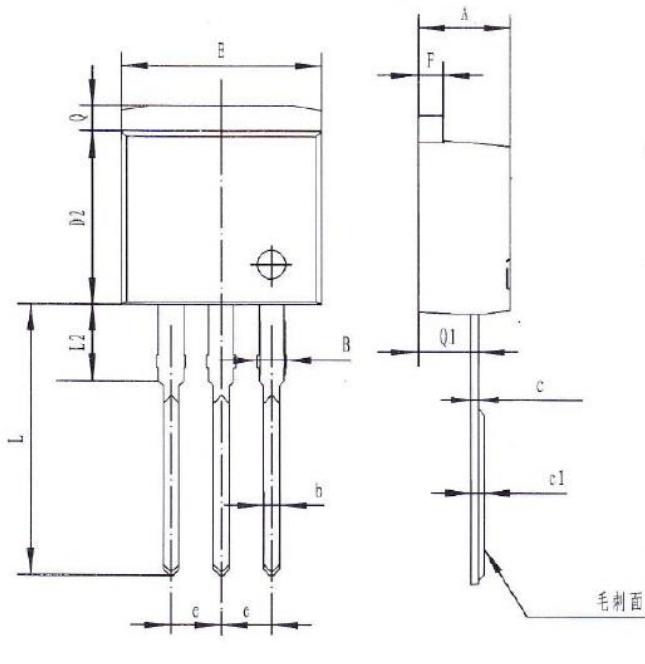




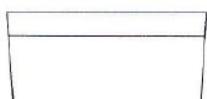
JCS4N65C

外形尺寸 PACKAGE MECHANICAL DATA
TO-262

单位 Unit: mm



符号 symbol	MIN	MAX
A	4.40	4.90
B	1.10	1.40
b	0.70	0.95
c	0.30	0.60
c1	0.33	0.63
D2	8.20	9.20
E	9.60	10.50
e	2.39	2.69
F	1.20	1.35
L	13.11	14.61
L2	3.55	4.05
Q	1.10	1.40
Q1	2.65	2.85



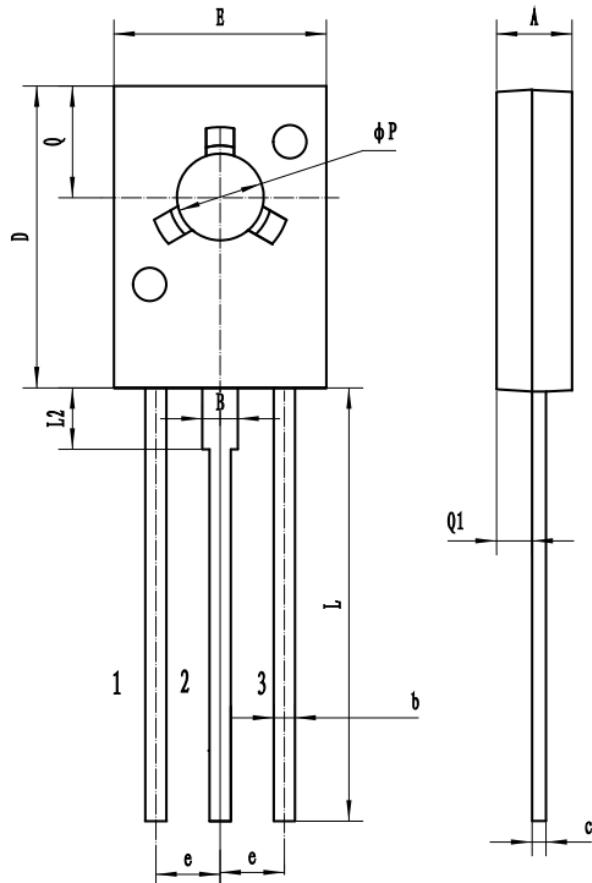


JCS4N65C

外形尺寸 PACKAGE MECHANICAL DATA

TO-126-K1

单位 Unit: mm



符号 symbol	MIN	MAX
A	2.50	2.90
B	1.22	1.47
b	0.60	0.90
c	0.30	0.70
D	10.50	11.10
E	7.10	8.10
e	2.19	2.39
L	15.30	15.70
L2	2.10	2.30
Q	3.80	4.20
Q1	1.07	1.47
P	3.00	3.20



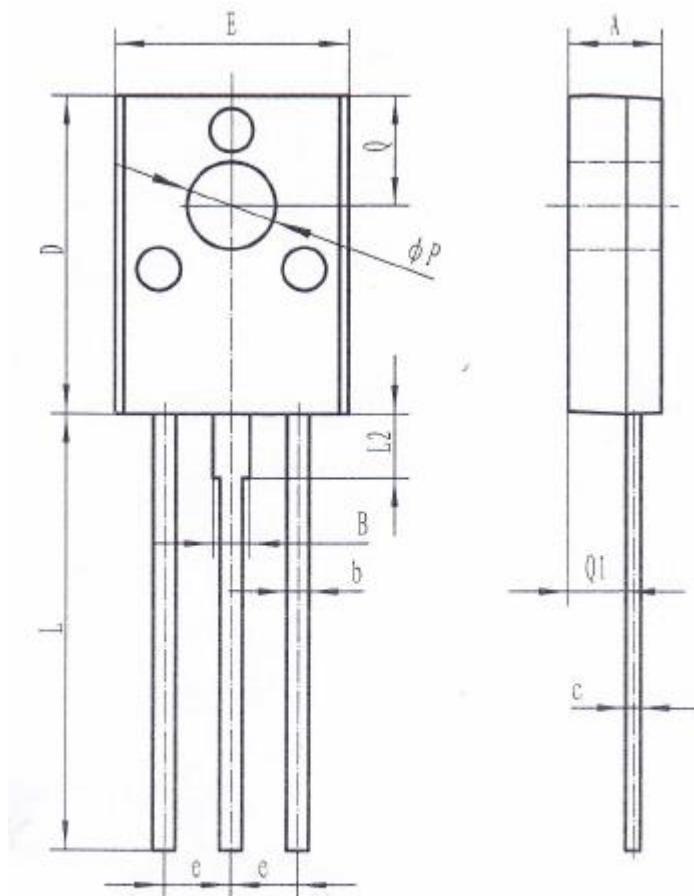


JCS4N65C

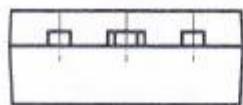
外形尺寸 PACKAGE MECHANICAL DATA

TO-126F

单位 Unit: mm



符号 symbol	MIN	MAX
A	3.10	3.30
B	1.22	1.47
b	0.60	0.90
c	0.45	0.70
D	10.50	11.20
E	7.50	8.50
e	2.29 TYP	
L	15.00	16.00
L2	2.10	2.30
Q	3.60	4.00
Q1	1.80	2.20
P	2.95	3.15



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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
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4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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